

KBJ6005 THRU KBJ610

Glass Passivated Single-Phase Bridge Rectifier

Reverse Voltage 50 to 1000 V

Forward Current 4 A

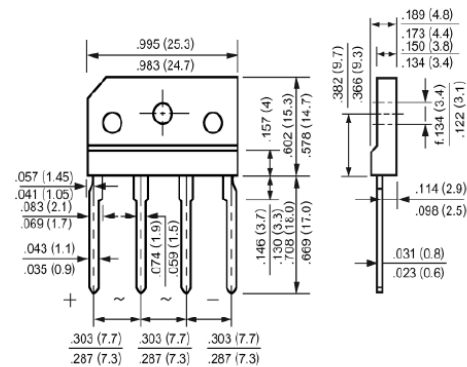
KBJ

Features

- Glass passivated chip junction
- Ideal for printed circuit board
- Plastic material has Underwriters Laboratory Flammability Classification 94V-0
- Reliable low cost construction utilizing molded plastic technique

Mechanical Data

- Case: Molded plastic, KBJ
- Epoxy: UL94V-0 rate flame retardant
- Terminals: Leads solderable per MIL-STD-202, Method 208 guaranteed
- Mounting Position: Any



Dimensions in inches and (millimeters)

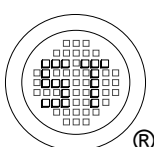
Maximum Ratings and Electrical Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

Parameter	Symbols	KBJ6005	KBJ601	KBJ602	KBJ604	KBJ606	KBJ608	KBJ610	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Average Rectified Rectified Current at $T_C = 110^\circ C$	$I_{F(AV)}$	6							A
Non-repetitive Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	150							A
Maximum Forward Voltage at 3 A DC	V_F	1							V
Maximum Reverse Current at Rated DC Blocking Voltage	I_R	5 500							μA
Typical Junction Capacitance ¹⁾	C_j	80							pF
Typical Thermal Resistance ²⁾	$R_{\theta JC}$	1.5							$^\circ C/W$
Operating Junction Temperature Range	T_j	- 55 to + 150							$^\circ C$
Storage Temperature Range	T_{stg}	- 55 to + 150							$^\circ C$

¹⁾ Measured at 1 MHz and applied reverse voltage of 4 V DC

²⁾ Thermal Resistance from Junction to Case with Device Mounted on 75 mm X 75 mm X 1.6 mmCu Plate Heatsink.



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FIG.1- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT PER BRIDGE ELEMENT

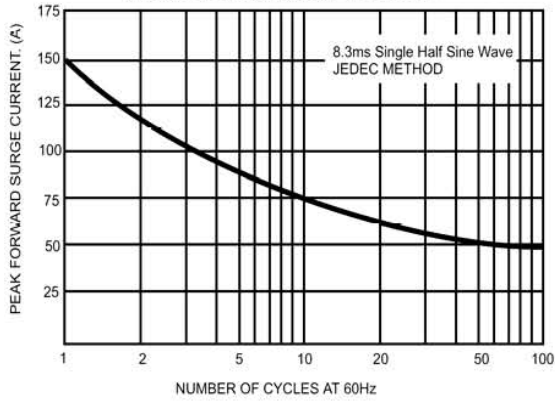


FIG.2- MAXIMUM FORWARD CURRENT DERATING CURVE

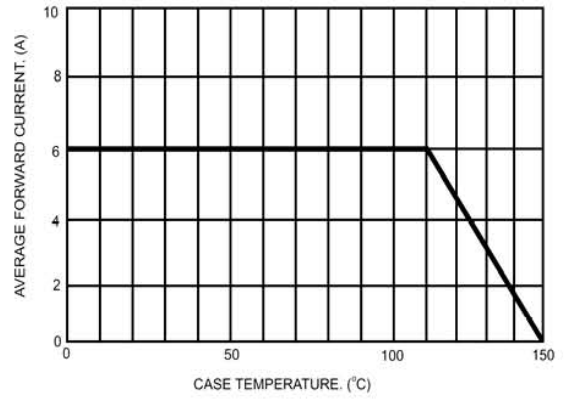


FIG.3- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS PER BRIDGE ELEMENT

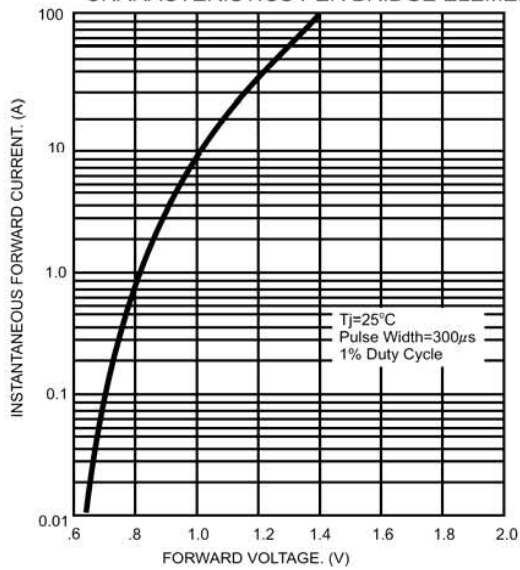
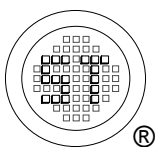
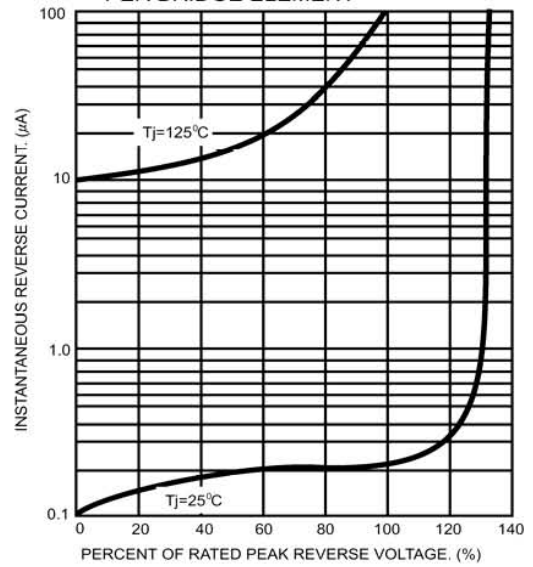


FIG.4- TYPICAL REVERSE CHARACTERISTICS PER BRIDGE ELEMENT



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